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Capacitively-coupled resonators for terahertz planar-Goubau-line filters

Juan Cabello-Sánchez, *Graduate Student Member, IEEE*, Vladimir Drakinskiy, Jan Stake, *Senior Member, IEEE*, Helena Rodilla, *Senior Member, IEEE*

Abstract—Low-loss planar Goubau lines show promising potential for terahertz applications. However, a single-wire waveguide exhibits less design freedom than standard multi-conductor lines, which is a significant constraint for realizing standard components. Existing filters for planar Goubau line lack clear design procedures preventing the synthesis of an arbitrary filter response. In this work, we present a design for a bandpass/bandstop filter for planar Goubau line by periodically loading the line with capacitively-coupled $\lambda/2$ resonators, which can be easily tuned by changing their electrical length. The filter's working principle is explained by a proposed transmission-line model. We designed and fabricated a passband filter centered at 0.9 THz on a 10- μm silicon-membrane substrate and compared measurement results between 0.5 THz and 1.1 THz to electromagnetic simulations, showing excellent agreement in both S_{11} and S_{21} . The measured passband has an insertion loss of 7 dB and a 3-dB bandwidth of 31%. Overall, the proposed filter design has good performance while having a simple design procedure.

Index Terms—Filters, periodic structures, planar Goubau line, on-wafer measurements, scattering parameters, silicon membrane, single-metal strip, terahertz waveguides, vector network analyzer (VNA)

I. INTRODUCTION

The development of efficient radio-frequency technology and components at terahertz (THz) frequencies [1] is essential for improving the performance and possibilities of THz applications, such as radio-astronomy [2], security [3], medical applications [4], telecommunications [5], pharmaceutical quality control [6], and biomolecular dynamics [7]. When planar technology is required—for its good integration, ease of fabrication, and low cost—it is necessary to minimize the high power losses present at THz frequencies to have good circuit performance. A fundamental way to minimize losses is to use power-efficient transmission lines. Some of the most used metal planar waveguides at THz frequencies include coplanar waveguide [8], coplanar stripline [9], microstrip [10], and planar Goubau line (PGL) [11]. As opposed to typical transmission lines based on multiple conductors [12], the PGL

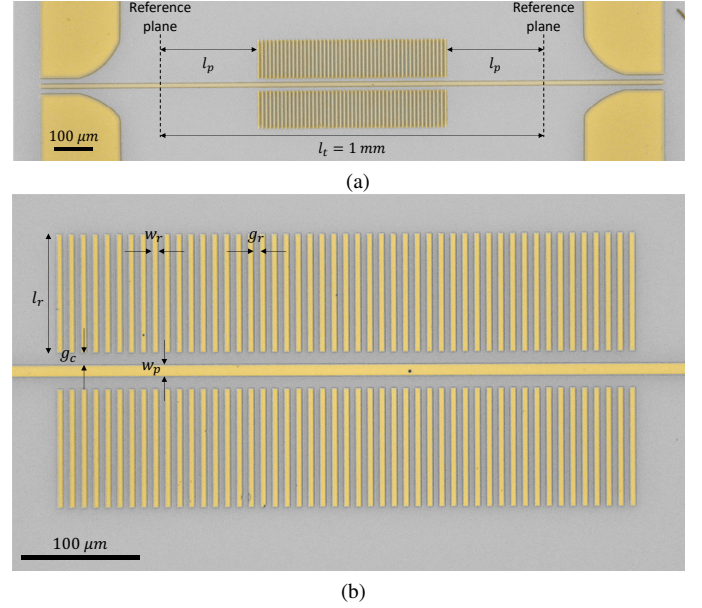


Fig. 1: False color micrographs of (a) the fabricated PGL filter with coplanar waveguide transitions on the sides, and (b) zoomed-in of the PGL filter with 49 resonator pairs, showing its dimension parameters. The gold and the high-resistivity silicon membrane are shown in golden and grey colors, respectively.

is a single-conductor planar waveguide consisting of a metal strip on top of a dielectric material, and to the best of the authors' knowledge its properties were first mentioned in [13], [14]. The PGL is the planar version of the Goubau line [15], [16] whose propagation mode is similar to the Sommerfeld or Zenneck waves [17] with a field that decays exponentially in the transverse direction. Similarly, the PGL can propagate a quasi-transverse-magnetic surface wave, which spreads radially from its single conductor, covering a large cross-section, and at the same time has higher field intensity at the edges of its conducting strip. Its propagation conditions depend on the electrical thickness of its substrate [18], where electrically-thin substrates minimize losses and dispersion. The dispersion, effective refractive index, field confinement, and ohmic losses can be increased by adding periodic corrugations or grooves [19], a concept explored by Goubau in 1950 [15], and sometimes referred to as spoof surface plasmon polariton waveguides [20]. Without corrugations, the PGL has shown to have one of the highest power efficiencies for metal planar waveguides [21], thus being a good candidate for circuit design at THz frequencies.

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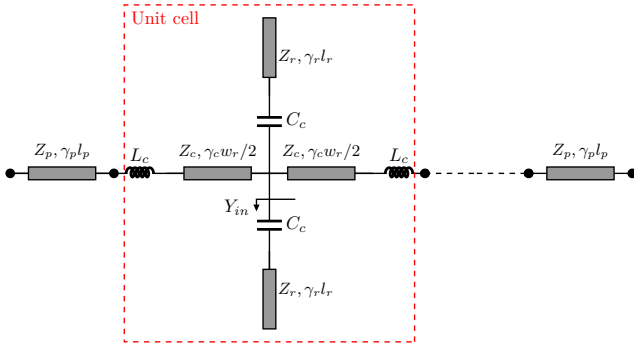


Fig. 2: Transmission-line model of the periodic filter consisting of repeating unit cells of capacitively-coupled open-ended resonators.

Designing circuit elements for PGL remains challenging due to its lack of ground plane. Despite this, several filtering circuit elements have been published for PGL, including stopband elements based on corrugations in the line [22] and resonators [23]–[26]. However, previously published resonating elements for PGL lack a clear design methodology that would allow them to synthesize any given filter response. In [22], it is unclear how to design line corrugations to produce an arbitrary stopband or if ring resonators can be used together to achieve a wider stopband. The resonators used in [23]–[26] can produce narrow stopbands, but they have not been tested by combining several resonators to achieve a broader bandwidth response.

This paper proposes a PGL filter based on periodic $\lambda/2$ resonators capacitively coupled to the PGL. The resonant frequency of the resonators can be easily tuned by changing the length of the resonating lines. The paper is organized as follows: section II contains the method, divided in transmission-line model (section II-A), design of a bandpass filter at 0.9 THz (section II-B), filter fabrication (section II-C), and measurement setup (section II-D). Finally, in section III, we present the results, and the conclusion in section IV.

II. METHOD

The proposed terahertz filter consists of a PGL periodically loaded with capacitively-coupled $\lambda/2$ resonators in a balanced configuration, see Fig. 1. The resonators are physically separated from the PGL to not short-circuit its propagating mode but close enough to produce coupling between the PGL and resonators. The input impedance presented by the shunt resonators along the line creates a frequency response with stopbands [27] when the resonators exhibit impedances close to a short-circuit. The periodic structure of N equal resonator pairs in cascade increases the bandwidth of the stopbands and, thereby, produces sharper and narrower passbands. The layout parameters of the filter (Fig. 1b) are the PGL's width, w_p ; resonator's length, l_r , gap, g_r , and width, w_r ; and the line-resonator coupling gap, g_c .

This section describes the transmission-line model, design, fabrication process, and on-wafer measurement setup to demonstrate a bandpass PGL filter centered at 0.9 THz fabricated on a silicon membrane.

A. Transmission-line model

Herein, an equivalent transmission-line model [28] is proposed to explain the rather complex electromagnetic wave propagation through the filtering structure. The filter, consisting of repeating resonators along the PGL, can be modeled as periodic unit cells of length $l_c = g_r + w_r$. Each unit cell represents a section of the PGL central filter strip with a coupled resonator-pair and two half resonator-gaps on both sides, modeled as shown in Fig. 2. The inductances, L_c , represent an electrically-short high-impedance line section with length $g_r/2$. The unit-cell model does not consider any coupling to neighboring resonators.

Two types of planar waveguides are used in the unit-cell model: coplanar waveguides (even mode) for the central line crossing the filter, γ_c and Z_c ; and parallel metal strips (even mode) for the waves excited in the coupled resonators, γ_r , and Z_r . No coplanar waveguide odd modes will be excited in the central line due to the symmetry of the filter [29]. Since the separation of contiguous resonators is much smaller than the wavelength, the excitation of the odd coplanar-stripline mode can be neglected [30]. Higher-order modes in the PGL decay rapidly, similarly to the Goubau line's [31], [32], and therefore were also neglected. Naturally, the line feeding the filter was modeled as a PGL with γ_p and Z_p .

The resonator's electrical length, $\gamma_r l_r$, determines the resonance frequency of the filter's stopband, as it can produce an input admittance, Y_{in} , in shunt with the main line, which tends to infinity at the stopband frequencies. The resonant frequencies of the capacitance-resonator can be found by applying transmission-line theory and calculating Y_{in} as a function of frequency. Y_{in} for a single coupled resonator is:

$$Y_{in} = \frac{j\omega C_c \tanh \gamma_r l_r}{\tanh \gamma_r l_r + j\omega C_c Z_r}, \quad (1)$$

where ω is the angular frequency and C_c is the coupling capacitance. The properties of the unit cell shown in Fig. 2 can be calculated by cascading the $ABCD$ matrices of each element as:

$$[U] = [C][L][Y][L][C], \quad (2)$$

where $[C]$, $[L]$, and $[Y]$ are the $ABCD$ matrices of a coplanar waveguide, a series inductor, and a shunt Y_{in} admittance, given by:

$$[C] = \begin{bmatrix} \cosh(\gamma_c w_r/2) & \sinh(\gamma_c w_r/2) Z_c \\ \sinh(\gamma_c w_r/2)/Z_c & \cosh(\gamma_c w_r/2) \end{bmatrix} \quad (3a)$$

$$[L] = \begin{bmatrix} 1 & j\omega L_c \\ 0 & 1 \end{bmatrix} \quad (3b)$$

$$[Y] = \begin{bmatrix} 1 & 0 \\ Y_{in} & 1 \end{bmatrix}. \quad (3c)$$

Then, the $ABCD$ matrix of the proposed model with a filter with N unit cells and a total PGL length of l_t is

$$[F] = [P][U]^N[P], \quad (4)$$

where $[P]$ is the $ABCD$ matrix corresponding to a PGL with length $l_p = (l_t - Nl_c)/2$ (see Fig. 2)

$$[P] = \begin{bmatrix} \cosh(\gamma_p l_p) & \sinh(\gamma_p l_p) Z_p \\ \sinh(\gamma_p l_p)/Z_p & \cosh(\gamma_p l_p) \end{bmatrix}. \quad (5)$$

B. Filter design

A 0.9-THz passband filter was designed, simulated and fabricated on a 10- μm thick high-resistivity ($\rho > 10\text{ k}\Omega\text{cm}$) suspended silicon membrane, with a bulk permittivity of $\epsilon_r = 11.7$ and $\tan\delta = 1.7 \cdot 10^{-5}$ [33], and using gold as conductor ($\sigma = 4.1 \times 10^7\text{ S/m}$). An electrically-thin suspended substrate helps reduce dielectric and radiation losses, crucial at THz frequencies. The radiation losses are minimized by having a higher phase constant, β , in the planar waveguides than in the undesired substrate modes [34]–[36]. With the proposed substrate, the critical frequencies for coupling to substrate modes [37] are calculated to be beyond 5 THz, and for second-order substrate modes, the cut-off frequency is around 4.6 THz.

The PGL was designed with a relatively large strip width of $w_p = 10\text{ }\mu\text{m}$, which decreases conductor loss [38]. For the resonator width and gap, we took $w_r = 5\text{ }\mu\text{m}$ and $g_r = 5\text{ }\mu\text{m}$ to guarantee sub-wavelength structure and operate well below the Bragg frequency [39]. In our case $\text{Im}(\gamma_c)(w_r + g_r) = \pi$ around 5 THz, thus we operate well below the Bragg frequency. We chose a coupling gap of $g_c = 10\text{ }\mu\text{m}$, which coupled the resonators while not short-circuiting the line's propagating mode.

After choosing the substrate and filter layout dimensions, the propagation constants and impedances of the three lines involved in the model were calculated with electromagnetic simulations using absorbing boundary conditions. Port sizes were a vacuum wavelength at the lowest frequency of analysis for PGL and resonators, and $3(w_p + 2g_c)$ by $2(w_p + 2g_c)$ for the rectangular port for the coplanar waveguide.

Each planar waveguide's propagation constant, $\gamma = \alpha + j\beta$, was obtained from the S-parameter results using 3D electromagnetic simulations based on the finite integration technique (CST Studio Suite). Simulation results were calculated between 50 GHz and 1.5 THz in several frequency bands and extrapolated down to dc. The excitation ports used inhomogeneous port accuracy enhancement, enabling accurate wideband results. The phase constants of the dielectric slab modes were calculated analytically [37]. The dispersion diagrams of the simulated planar waveguides used to model the filter are shown in Fig. 3a together with the fundamental transverse-electric and transverse-magnetic modes of the dielectric slab mode. As desired, all the planar waveguides show a higher phase constant than the dielectric slab modes present in the substrate, which minimizes radiation loss. The attenuation constants of the planar waveguides, α , are shown in Fig. 3b, presenting results proportional to frequency.

The characteristic impedance of the lines was calculated using 2D finite-element-method simulations (COMSOL multiphysics) of the cross-section of the planar waveguides

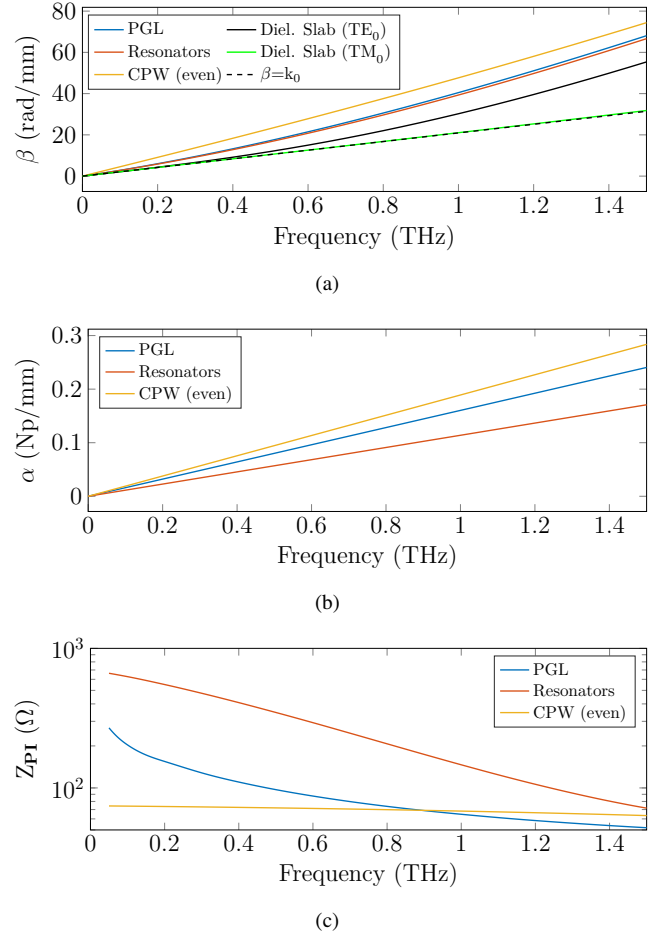


Fig. 3: Simulated wave-propagating properties vs. frequency for PGL, resonators, and coplanar waveguide (CPW), for the used substrate. (a) Phase constant of the planar waveguides compared to the dielectric-slab modes. (b) Attenuation constants. (c) Characteristic impedance defined from eq. (6).

between 50 GHz and 1.5 THz, using the power-current definition [40]:

$$Z_{PI} = \frac{2P_{avg}}{|I|^2} = 2 \frac{\iint_A \langle \vec{S} \rangle d\vec{A}}{\left| \oint_C \vec{H} d\vec{l} \right|^2} \quad (6)$$

where P_{avg} denotes the time-averaged power of the waveguide, and I is the current. The characteristic impedance results of the planar waveguides used for modeling the filter are shown in Fig. 3c, neglecting the imaginary part of the PGL's impedance [41].

With the above values of w_r , g_r and g_c , we fitted the values of C_c and L_c to 1.5 fF and 7 pH, respectively, by comparing 3D electromagnetic simulations of a single resonator pair of arbitrary length with its model, taking γ_r and Z_r from a 5- μm PGL strip. With the resulting values of C_c and L_c , a stopband centered around 0.6 THz requires a resonator length of $l_r = 100\text{ }\mu\text{m}$, producing a passband response around 0.9 THz. Fig. 4 compares the scattering parameters of the proposed model and electromagnetic simulation results of a filter with a single resonator pair of length $l_r = 100\text{ }\mu\text{m}$, showing fair agreement, and replicating the resonances in transmission.

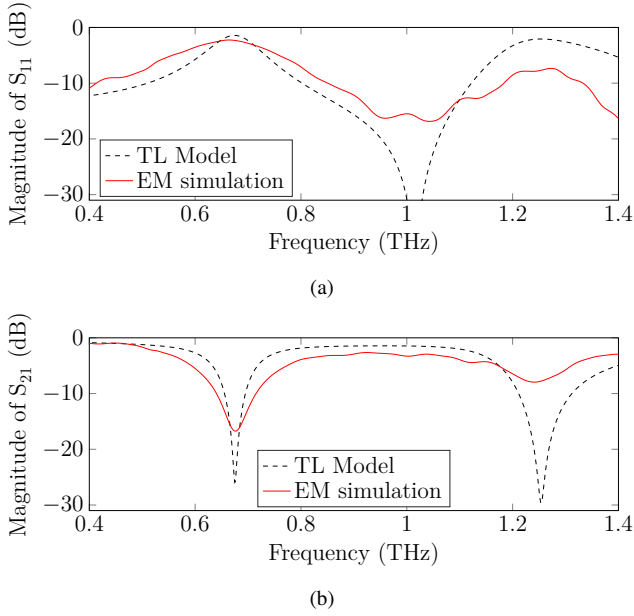


Fig. 4: S-parameter comparison of the transmission-line model and electromagnetic simulations for a single-resonator-pair filter. The model shows to properly reproduce the pass- and stopbands of the filter. (a) $|S_{11}|$ and (b) $|S_{21}|$.

Fig. 5 shows the modeled transmission, S_{21} , of the proposed filter with $l_r = 100 \mu\text{m}$ as a function of the number of unit cells, while maintaining the total length of the PGL at a constant total size of $l_t = 1 \text{ mm}$. As can be seen, the bandwidth of the stopband increases with the number of unit cells and saturates around 20, being confined to regions where $\pi(n - 0.5) < \beta_r l_r < \pi n$, $\forall n \in \mathbb{N}$. Due to the capacitive coupling, resonances are up-shifted from odd multiples of $\beta_r l_r = \pi/2$. We chose $N = 49$ unit cells for the fabricated filter.

Finally, a transition from coplanar waveguide to PGL was included in the layout (Fig. 1a) for on-wafer characterization using ground-signal-ground probes. The transition was designed to minimize insertion losses by exponentially changing its line impedance to reduce reflections and by using a quarter-wave transition at 0.9 THz to lower line losses [42].

C. Fabrication

The suspended PGL filter was fabricated using a silicon-on-insulator (SOI) wafer from University Wafers. We used a high-resistivity ($>10 \text{ k}\Omega \text{ cm}$), undoped, $10\text{-}\mu\text{m}$ device layer; $1\text{-}\mu\text{m}$ buried oxide layer grown on a high-resistivity, $400\text{-}\mu\text{m}$ thick, silicon handle wafer.

In Fig. 6a, the complete process flow is outlined. The fabrication process begins by defining the circuit using electron-beam lithography (#1,2), followed by metal deposition (#3) and lift-off (#4). The conductor metallization consists of a 10-nm titanium adhesive layer and a 350-nm gold layer, evaporated in an ultra-high vacuum chamber. Prior to the backside processing, the front side, with the circuit layer, is first protected with a thick resist and then mounted topside-down on a 6-inch carrier wafer. The backside process starts by sputtering a 20-nm aluminum etch mask layer (#5,6).

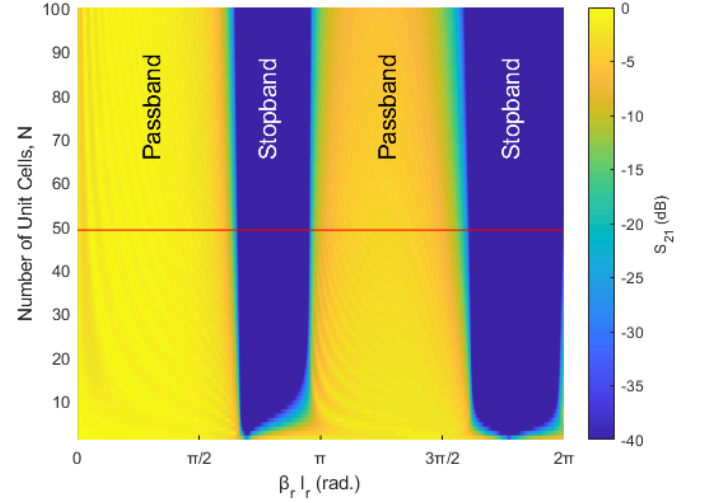


Fig. 5: Magnitude of transmission, $|S_{21}|$, calculated using the transmission-line model from Fig. 2, of the proposed PGL filter as a function of the number of resonators, N , and the normalized frequency, $\beta_r l_r$. Values in dark blue color have a $|S_{21}| \leq 40 \text{ dB}$. The fabricated filter has 49 unit cells, marked with the red line.

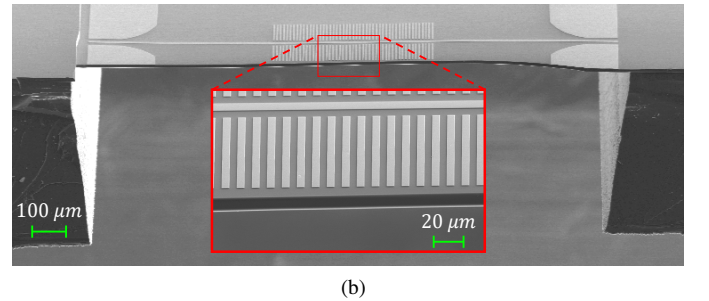
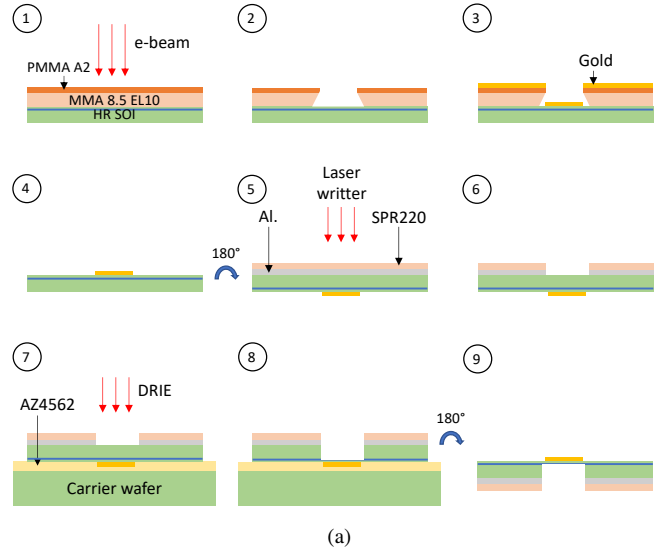
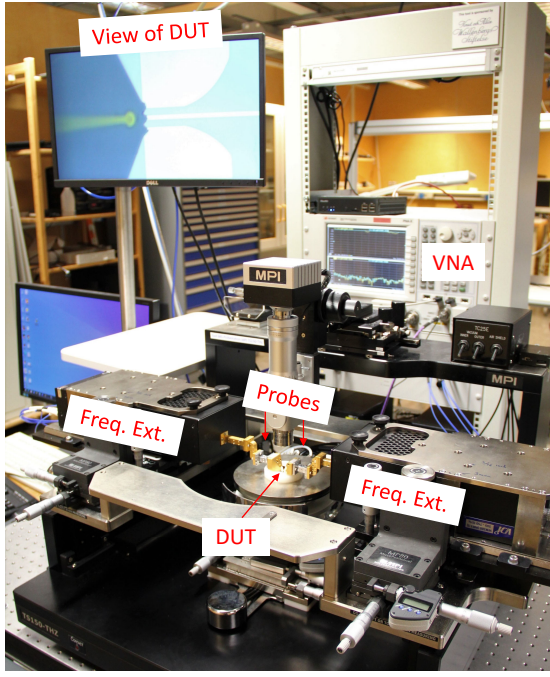
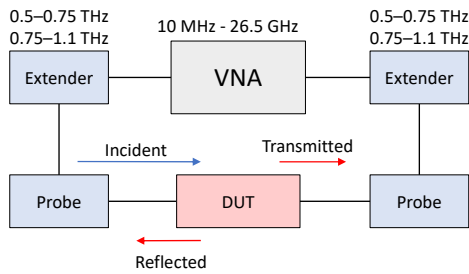


Fig. 6: (a) Sketch of the fabrication steps of the proposed silicon-on-insulator chip (NB! The drawings are not in scale). (b) Scanning-electron-microscope image of the filter fabricated on the high-resistivity silicon membrane. The inset shows detail of the membrane and resonators. Unfortunately, the left side of the membrane broke when cleaving the chip for the picture.



(a)



(b)

Fig. 7: (a) Picture of the measurement setup showing the probe station with the vector network analyzer (VNA), frequency extenders, and on-wafer probes. (b) Sketch of the measurement setup.

Openings for the membrane cavities are then defined in a photoresist (SPR220-3.0) using a direct laser writer. The chip is mounted on a silicon carrier wafer using a photoresist (AZ4562) and baked (#7). Then, the silicon carrier wafer with the chip is dry-etched by deep reactive ion etching (Bosch process) in SF_6 and O_2 atmosphere, using C_2F_8 as passivation. The etch rate is about $1\ \mu\text{m}$ per cycle. The high selectivity toward dry etching between silicon and silicon dioxide ensures that the etching process will stop when the buried oxide is reached (#8). After etching, the chip is released from the carrier wafer by dissolving the protecting resist in acetone for 48 hours (#9). Finally, any remaining resist residues are cleaned using an O_2 -plasma dry etching.

A scanning-electron-microscope photograph of the fabricated suspended PGL circuit is shown in Fig. 6b. Compared to our previous work using a soft plastic film substrate [43], the suspended silicon substrate has the advantage of having the entire device on top of the suspended membrane, improving the repeatability of measurements and removing supporting substrate interfaces.

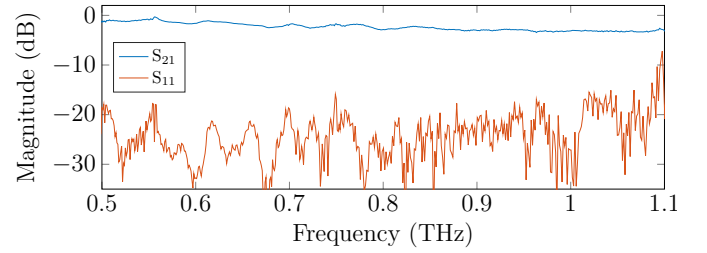


Fig. 8: Measured S-parameters for a 1-mm-long PGL fabricated in the same high-resistivity silicon membrane.

D. Measurement set-up

The PGL filter was characterized by measuring the S-parameters between 0.5 THz and 1.1 THz using a vector network analyzer (Keysight N5242A) with frequency extenders (VDI WR1.5SAX and WR1.0SAX) and DMPI T-Wave ground-signal-ground probes [44] (Fig. 7). The intermediate-frequency bandwidth was set to 100 Hz. The measurements were calibrated with dedicated multi-line Thru-Reflect-Line standards for PGL [42] fabricated on the same chip. Calibrating allows to set the reference plane in the PGL (see Fig. 1a) and to de-embed the coplanar waveguide transition. The lines used for calibration have an electrical length of $\lambda/4$, $3\lambda/4$, and $11\lambda/4$ at 0.91 THz, with an effective refractive index of $n_e = 1.88$. The chip was placed on top of a polyethylene ($\epsilon_r = 2.3$ and $\tan\delta = 0.004$ at 1 THz [45]) supporting substrate to isolate the DUT from the probe station's metal chuck. The suspended $10\text{-}\mu\text{m}$ silicon membrane of the chip has enough mechanical strength to support the pressure from on-wafer probing.

III. RESULTS

First, Fig. 8 presents the measured S-parameters of a 1-mm-long PGL with no resonators. The loss goes from 1 dB/mm at 0.5 THz to 3 dB/mm for 1.1 THz, having relatively low losses for a metal planar waveguide at THz frequencies. The magnitude of S_{11} is at the noise floor of the measurement setup.

In Fig. 9, the measured S-parameters of the filter from 0.5 THz to 1.1 THz are shown together with 3D simulations and the transmission-line model. The results from electromagnetic simulations show excellent agreement with measurements. The minor difference between simulation and experimental results in S_{21} can be explained by fabrication tolerances, variation in thin-film material properties, and calibration uncertainties. The transmission-line model describes well the passband/stopband regime with a slight frequency shift which becomes more noticeable at higher frequencies. The filter's S_{21} shows a stopband and a passband centered at 0.6 THz and 0.9 THz, respectively, with 3-dB bandwidth of 27% and 31%, respectively. The bandpass has insertion loss of 7 dB—or about 4 dB more than a PGL of the same length without resonators (Fig. 8)—which are competitive compared to planar filters measured in the sub-millimeter band (Table I). Both S_{11} and S_{21} show an asymmetrical passband response, with steeper band transitions at higher passband frequencies. This effect could be explained

TABLE I: State-of-the-art in planar filters measured above 300 GHz

f_c (GHz)	3-dB bandwidth (%)	Waveguide	Insertion losses	Reference
311	7 *	Substrate-integrated waveguide	7 dB	[46]
317	2.6 §	Planar Goubau line	7.5 dB	[25]
337	15 *	Substrate-integrated waveguide	2 dB	[47]
350	13 *	Coplanar waveguide	1 dB †	[48]
354	0.13 *	Microstrip	6 dB †	[49]
585	24 §	Microstrip	10 dB	[50]
935	31 *	Planar Goubau line	7 dB	This work

* Passband. § Stopband. † Superconductor

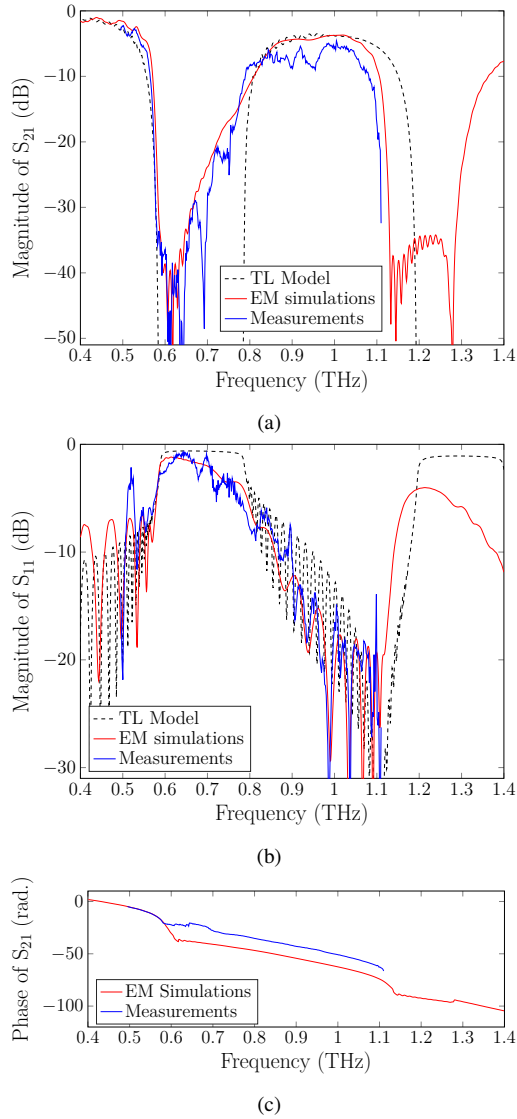


Fig. 9: S-parameter comparison of the transmission-line model, electromagnetic simulations, and measurements for the fabricated 49-unit-cell 0.9 THz bandpass filter (Fig. 1b). Measurements agree well with both electromagnetic simulations and the transmission-line model. (a) shows $|S_{21}|$ results and (b) shows $|S_{11}|$ results, both on decibels. (c) Phase of S_{21} against frequency, showing low dispersion of the line in the passband.

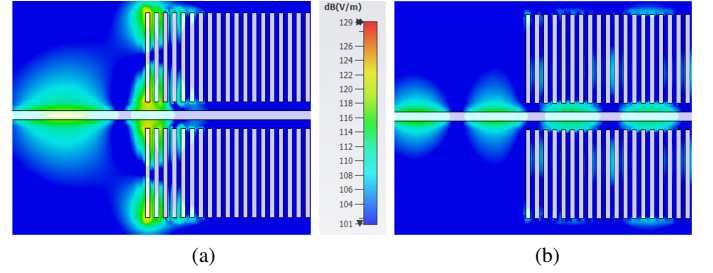


Fig. 10: Simulations of the electromagnetic fields in the PGL filter. The magnitude of the electric field in logarithmic scale at (a) stopband frequency, 0.6 THz, and at (b) passband frequency, at 0.9 THz. Scale bar applies to both subfigures.

by an increase in the effective refractive index at higher passband frequencies caused by the periodic resonators in the filter. The ripples in S_{11} result from the impedance mismatch between the main PGL and the Bloch impedance of the periodic filter. The noise level limits in the measurement setup are around -50 dB for S_{21} , and around -22 dB for S_{11} . Measurements showed a high degree of repeatability across different probe landings, filter structures, and calibrations.

The measured phase of S_{21} is plotted in Fig. 9c, showing low measured dispersion in the passband, and good agreement with simulated results. The transmission-line model overestimates the phase's slope of the filter, and therefore it was omitted.

Although simplified, the proposed transmission-line model describes well the magnitude response of the filter demonstrating that the operating principle of the filter can be mostly explained by the periodic placement of coupled $\lambda/2$ resonators and that other possible effects like coupling between neighboring resonators do not play a key role. The model accuracy could be further improved by recalculating C_c for each of the 49 unit cells—since we kept the same value calculated for a single unit cell—, and taking into account additional parasitic circuit elements.

The simulated electric field distribution of the filter in Fig. 10 explains the filtering behavior. When operating at the stopband, at 0.6 THz (Fig. 10a), the resonators resonate and produce a shunt short-circuit in the main PGL, which prohibits wave propagation. Fig. 10b shows the E-field of the filter when operating at passband at 0.9 THz, where the waves can

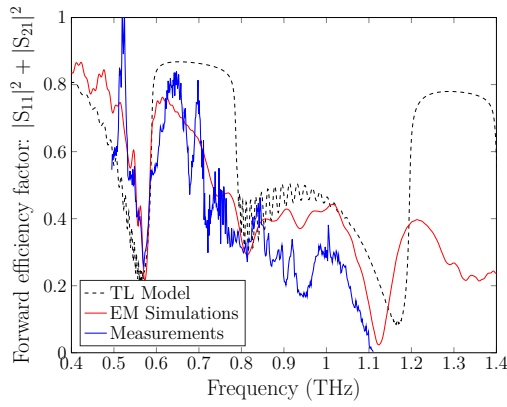


Fig. 11: Forward efficiency factor vs. frequency, showing the loss of the filter.

propagate through the filter with a propagating mode similar to that of a coplanar waveguide's even mode.

The forward efficiency factor ($|S_{11}|^2 + |S_{21}|^2$) is presented in Fig. 11, where increased loss is observed at the transition from a passband to a stopband since currents increase. The differences between simulation and measurement results between 0.8 and 1.1 THz are a consequence of the difference between the levels of S_{21} . And similarly, the peak around 520 GHz can be explained by the spurious peak at the same frequency in S_{11} .

IV. CONCLUSION

In summary, we present a planar-Goubau-line terahertz bandpass/bandstop filter which can be easily tuned by changing the electrical length of the periodic capacitively-coupled $\lambda/2$ resonators. The working principle of the periodic filter was confirmed by a simple transmission-line model, which agrees with simulations and measurements. The proposed filter design was validated by fabricating and measuring a periodic structure with 49 unit cells with a passband centered around 0.9 THz, showing good agreement between simulations and measurements, and a relatively low insertion loss of 7 dB compared to planar filters measured in the sub-millimeter band. Future work could explore the design and tune of a filter response by modulating the length of the different capacitively-coupled resonators [27], and further elaborate the transmission-line model.

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REFERENCES

- [1] D. M. Mittleman, "Perspective: Terahertz science and technology," *Journal of Applied Physics*, vol. 122, no. 23, pp. 1–12, 2017, doi: 10.1063/1.5007683.
- [2] T. Phillips and J. Keene, "Submillimeter astronomy (heterodyne spectroscopy)," *Proceedings of the IEEE*, vol. 80, no. 11, pp. 1662–1678, 1992, doi: 10.1109/5.175248.
- [3] R. Appleby and H. B. Wallace, "Standoff detection of weapons and contraband in the 100 GHz to 1 THz region," *IEEE Transactions on Antennas and Propagation*, vol. 55, no. 11 I, pp. 2944–2956, 2007, doi: 10.1109/TAP.2007.908543.
- [4] E. Pickwell and V. P. Wallace, "Biomedical applications of terahertz technology," *Journal of Physics D: Applied Physics*, vol. 39, no. 17, pp. 301–310, 2006, doi: 10.1088/0022-3727/39/17/R01.
- [5] H. J. Song and T. Nagatsuma, "Present and future of terahertz communications," *IEEE Transactions on Terahertz Science and Technology*, vol. 1, no. 1, pp. 256–263, 2011, doi: 10.1109/THZ.2011.2159552.
- [6] P. Bawuah and J. A. Zeitler, "Advances in terahertz time-domain spectroscopy of pharmaceutical solids: A review," *TrAC - Trends in Analytical Chemistry*, vol. 139, p. 116272, 2021, doi: 10.1016/j.trac.2021.116272.
- [7] G. Acbas, K. A. Niessen, E. H. Snell, and A. G. Markelz, "Optical measurements of long-range protein vibrations," *Nature Communications*, vol. 5, pp. 1–7, 2014, doi: 10.1038/ncomms4076.
- [8] C. P. Wen, "Coplanar Waveguide: A Surface Strip Transmission Line Suitable for Nonreciprocal Gyromagnetic Device Applications," *IEEE Transactions on Microwave Theory and Techniques*, vol. 17, no. 12, pp. 1087–1090, 1969, doi: 10.1109/TMTT.1969.1127105.
- [9] J. B. Knorr and K. D. Kuchler, "Analysis of Coupled Slots and Coplanar Strips on Dielectric Substrate," *IEEE Transactions on Microwave Theory and Techniques*, vol. 23, no. 7, pp. 541–548, 1975, doi: 10.1109/TMTT.1975.1128624.
- [10] D. D. Grieg and H. F. Engelmann, "Microstrip—A New Transmission Technique for the Kilomegacycle Range," *Proceedings of the IRE*, vol. 40, no. 12, pp. 1644–1650, 1952, doi: 10.1109/JRPROC.1952.274144.
- [11] T. Akalin, A. Treizebré, and B. Bocquet, "Single-wire transmission lines at terahertz frequencies," *IEEE Transactions on Microwave Theory and Techniques*, vol. 54, no. 6, pp. 2762–2767, 2006, doi: 10.1109/TMTT.2006.874890.
- [12] K. Wu, M. Bozzi, and N. J. G. Fonseca, "Substrate Integrated Transmission Lines: Review and Applications," *IEEE Journal of Microwaves*, vol. 1, no. 1, pp. 345–363, 2021, doi: 10.1109/jmw.2020.3034379.
- [13] V. M. Temnov and O. S. Orlov, "The single-strip line is a new type of the integrated circuits for microwaves," in *2000 10th International Crimean Microwave Conference "Microwave and Telecommunication Technology", Crimico 2000*. IEEE, 2000, pp. 359–360, doi: 10.1109/CRMICO.2000.1256140.
- [14] W. Hong and Y. D. Lin, "Single-conductor strip leaky-wave antenna," *IEEE Transactions on Antennas and Propagation*, vol. 52, no. 7, pp. 1783–1789, 2004, doi: 10.1109/TAP.2004.829854.
- [15] G. Goubau, "Surface waves and their application to transmission lines," *Journal of Applied Physics*, vol. 21, no. 11, pp. 1119–1128, 1950, doi: 10.1063/1.1699553.
- [16] —, "Single-Conductor Surface-Wave Transmission Lines," *Proceedings of the IRE*, vol. 39, no. 6, pp. 619–624, 1951, doi: 10.1109/JRPROC.1951.233782.
- [17] H. Barlow and A. Cullen, "Surface waves," *Proceedings of the IEE - Part III: Radio and Communication Engineering*, vol. 100, no. 68, pp. 329–341, 1953, doi: 10.1049/pi-3.1953.0068.
- [18] D. Gacemi, A. Degiron, M. Baillergeau, and J. Mangeney, "Identification of several propagation regimes for terahertz surface waves guided by planar Goubau lines," *Applied Physics Letters*, vol. 103, no. 19, p. 1119, 2013, doi: 10.1063/1.4829744.
- [19] W. Rotman, "A Study of Single-Surface Corrugated Guides," *Proceedings of the IRE*, vol. 39, no. 8, pp. 952–959, 1951, doi: 10.1109/JRPROC.1951.273719.
- [20] S. A. Maier, S. R. Andrews, L. Martín-Moreno, and F. J. García-Vidal, "Terahertz surface plasmon-polariton propagation and focusing on periodically corrugated metal wires," *Physical Review Letters*, vol. 97, no. 17, pp. 1–4, 2006, doi: 10.1103/PhysRevLett.97.176805.
- [21] J. Cabello-Sánchez, H. Rodilla, V. Drakinskiy, and J. Stake, "Transmission Loss in Coplanar Waveguide and Planar Goubau Line between 0.75 THz and 1.1 THz," in *2018 43rd International Conference*

- on *Infrared, Millimeter, and Terahertz Waves (IRMMW-THz)*, Nagoya, 2018, pp. 1–2, doi: 10.1109/IRMMW-THz.2018.8510326.
- [22] T. Akalin and W. Padilla, “Plasmonic waveguides and metamaterial components at terahertz frequencies,” *APMC 2009 - Asia Pacific Microwave Conference 2009*, pp. 2444–2446, 2009, doi: 10.1109/APMC.2009.5385481.
- [23] L. Dazhang, J. Cunningham, M. B. Byrne, S. Khanna, C. D. Wood, A. D. Burnett, S. M. Ershad, E. H. Linfield, and A. G. Davies, “On-chip terahertz Goubau-line waveguides with integrated photoconductive emitters and mode-discriminating detectors,” *Applied Physics Letters*, vol. 95, no. 9, p. 092903, 8 2009, doi: 10.1063/1.3216579.
- [24] A. Treizebre, M. Hofman, and B. Bocquet, “Terahertz Spiral Planar Goubau Line Rejectors for Biological Characterization,” *Progress In Electromagnetics Research M*, vol. 14, no. July, pp. 163–176, 2010, doi: 10.2528/PIERM10072110.
- [25] W. C. Chen, J. J. Mock, D. R. Smith, D. R. Akalin, and W. J. Padilla, “Controlling Gigahertz and Terahertz Surface Electromagnetic Waves with Metamaterial Resonators,” *Physical Review X*, vol. 1, no. 2, p. 021016, 12 2011, doi: 10.1103/PhysRevX.1.021016.
- [26] A. K. Horestani, W. Withayachumnankul, A. Chahadih, A. Ghaddar, M. Zehar, D. Abbott, C. Fumeaux, and T. Akalin, “Metamaterial-inspired bandpass filters for terahertz surface waves on goubau lines,” *IEEE Transactions on Terahertz Science and Technology*, vol. 3, no. 6, pp. 851–858, 2013, doi: 10.1109/TTHZ.2013.2285556.
- [27] L. Young, G. L. Matthaei, and E. M. Jones, “Microwave Band-Stop Filters With Narrow Stop Bands,” *IRE Transactions on Microwave Theory and Techniques*, vol. MTT-10, no. 6, pp. 416–427, 1962, doi: 10.1109/TMTT.1962.1125549.
- [28] R. Marks and D. Williams, “A general waveguide circuit theory,” *Journal of Research of the National Institute of Standards and Technology*, vol. 97, no. 5, pp. 533–562, 1992, doi: 10.6028/jres.097.024.
- [29] M. Ribó and L. Pradell, “Circuit Model for a Coplanar-Slotline Cross,” *IEEE Microwave and Guided Wave Letters*, vol. 10, no. 12, pp. 511–513, 2000, doi: 10.1109/75.895085.
- [30] G. E. Ponchak, “Coplanar Stripline Series-Stub with even Mode Suppression,” *IEEE Microwave and Wireless Components Letters*, vol. 28, no. 11, pp. 963–965, 2018, doi: 10.1109/LMWC.2018.2869283.
- [31] L. W. Zelby, “Propagation modes on a dielectric coated wire,” *Journal of the Franklin Institute*, vol. 274, no. 2, pp. 85–97, 8 1962, doi: 10.1016/0016-0032(62)90398-8.
- [32] J. G. Fikioris and J. A. Roumeliotis, “Cutoff Wavenumbers of Goubau Lines,” *IEEE Transactions on Microwave Theory and Techniques*, vol. 27, no. 6, pp. 570–573, 1979, doi: 10.1109/TMTT.1979.1129673.
- [33] J. Dai, J. Zhang, W. Zhang, and D. Grischkowsky, “Terahertz time-domain spectroscopy characterization of the far-infrared absorption and index of refraction of high-resistivity, float-zone silicon,” *Journal of the Optical Society of America B*, vol. 21, no. 7, p. 1379, 2004, doi: 10.1364/JOSAB.21.001379.
- [34] D. B. Rutledge, S. E. Schwarz, and A. T. Adams, “Infrared and submillimetre antennas,” *Infrared Physics*, vol. 18, no. 5-6, pp. 713–729, 1978, doi: 10.1016/0020-0891(78)90094-5.
- [35] D. B. Rutledge, D. P. Neikirk, and D. P. Kasilingam, “Integrated-Circuit Antennas,” in *Infrared and millimeter waves*. New York: Academic, 1983, ch. 1, pp. 59–63.
- [36] D. Grischkowsky, I. N. Duling, J. C. Chen, and C. C. Chi, “Electromagnetic shock waves from transmission lines,” *Physical Review Letters*, vol. 59, no. 15, pp. 1663–1666, 10 1987, doi: 10.1103/PhysRevLett.59.1663.
- [37] L. Hatkin, “Analysis of Propagating Modes in Dielectric Sheets,” *Proceedings of the IRE*, vol. 42, no. 10, pp. 1565–1568, 1954, doi: 10.1109/JRPROC.1954.274764.
- [38] Y. Xu and R. G. Bosisio, “A comprehensive study on the planar type of Goubau line for millimetre and submillimetre wave integrated circuits,” *IET Microwaves, Antennas and Propagation*, vol. 1, no. 3, pp. 681–687, 2007, doi: 10.1049/iet-map:20050308.
- [39] A. F. Harvey, “Periodic and Guiding Structures at Microwave Frequencies,” *IRE Transactions on Microwave Theory and Techniques*, vol. 8, no. 1, pp. 30–61, 1960, doi: 10.1109/TMTT.1960.1124658.
- [40] S. A. Schelkunoff, “Impedance concept in wave guides,” *Quarterly of Applied Mathematics*, vol. II, pp. 1–15, 1944, doi: 10.1090/qam/11833.
- [41] D. Cavallo, W. H. Syed, and A. Neto, “Equivalent Transmission Line Models for the Analysis of Edge Effects in Finite Connected and Tightly Coupled Arrays,” *IEEE Transactions on Antennas and Propagation*, vol. 65, no. 4, pp. 1788–1796, 2017, doi: 10.1109/TAP.2017.2670616.
- [42] J. Cabello-Sánchez, H. Rodilla, V. Drakinskiy, and J. Stake, “Multiline TRL Calibration Standards for S-parameter Measurement of Planar Goubau Lines from 0.75 THz to 1.1 THz,” in *2018 IEEE/MTT-S International Microwave Symposium - IMS*, Philadelphia, PA, USA, 2018, pp. 879–882, doi: 10.1109/MWSYM.2018.8439138.
- [43] J. Cabello-Sánchez, V. Drakinskiy, J. Stake, and H. Rodilla, “On-Chip Characterization of High-Loss Liquids between 750 and 1100 GHz,” *IEEE Transactions on Terahertz Science and Technology*, vol. 11, no. 1, pp. 113–116, 2021, doi: 10.1109/TTHZ.2020.3029503.
- [44] M. F. Bauwens, N. Alijabbari, A. W. Lichtenberger, N. S. Barker, and R. M. Weikle, “A 1.1 THz micromachined on-wafer probe,” in *2014 IEEE MTT-S International Microwave Symposium (IMS2014)*, Tampa, FL, 2014, pp. 1–4, doi: 10.1109/MWSYM.2014.6848607.
- [45] N. Fuse, T. Takahashi, Y. Ohki, R. Sato, M. Mizuno, and K. Fukunaga, “Terahertz Spectroscopy as a New Tool for Insulating Material Analysis and Condition Monitoring,” *IEEE Insulating Magazine*, vol. 27, no. 3, pp. 26–35, 2011, doi: 10.1109/MEI.2011.5871366.
- [46] J. W. Holloway, G. C. Dogiamis, S. Shin, and R. Han, “220-to-330-GHz manifold triplexer with wide stopband utilizing ridged substrate integrated waveguides,” *IEEE Transactions on Microwave Theory and Techniques*, vol. 68, no. 8, pp. 3428–3438, 2020, doi: 10.1109/TMTT.2020.2997367.
- [47] F. Wang, V. F. Pavlidis, and N. Yu, “Miniaturized SIW Bandpass Filter Based on TSV Technology for THz Applications,” *IEEE Transactions on Terahertz Science and Technology*, vol. 10, no. 4, pp. 423–426, 2020, doi: 10.1109/TTHZ.2020.2974091.
- [48] J. Q. Ding, J. Hu, and S. C. Shi, “350-GHz Bandpass Filters Using Superconducting Coplanar Waveguide,” *IEEE Transactions on Terahertz Science and Technology*, vol. 11, no. 5, pp. 548–556, 2021, doi: 10.1109/TTHZ.2021.3071019.
- [49] A. Pascual Laguna, K. Karatsu, D. Thoen, V. Murugesan, B. Buijtenorp, A. Endo, and J. Baselmans, “Terahertz Band-Pass Filters for Wideband Superconducting On-Chip Filter-Bank Spectrometers,” *IEEE Transactions on Terahertz Science and Technology*, vol. 11, no. 6, pp. 635–646, 2021, doi: 10.1109/TTHZ.2021.3095429.
- [50] J. Cunningham, C. Wood, A. G. Davies, I. Hunter, E. H. Linfield, and H. E. Beere, “Terahertz frequency range band-stop filters,” *Applied Physics Letters*, vol. 86, no. 21, pp. 1–3, 2005, doi: 10.1063/1.1938255.



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